Vishay High Power Products

FlipKY[®] Chip Scale Package Schottky Barrier Rectifier

I?R

SHA



FlipKY[®]

PRODUCT SUMMARY				
I _{F(AV)}	1 A			
V _R	30 V			

FEATURES

- Ultra low V_F per footprint area
- Low leakage
- Low thermal resistance
- One-fifth footprint of SMA
- Super low profile (0.6 mm)
- Available tested on tape and reel

APPLICATIONS

- Reverse polarity protection
- Current steering
- Freewheeling
- Flyback
- Oring

DESCRIPTION

Vishay's FlipKY[®] product family utilizes wafer level chip scale packaging to deliver Schottky diodes with the lowest V_F to PCB footprint area in industry. The four bump 1.5 x 1.5 mm devices can deliver up to 1 A and occupy only 2.3 mm² of board space. The anode and cathode connections are made through solder bump pads on one side of the silicon enabling designers to strategically place the diodes on the PCB. This design not only minimizes board space but also reduces thermal resistance and inductance, which can improve overall circuit efficiency.

Typical applications include hand-held, portable equipment such as cell phones, MP3 players, bluetooth, GPS, PDAs, and portable hard disk drives where space savings and performance are crucial.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	MAX.	UNITS		
V _{RRM}		30	V		
I _{F(AV)}	Rectangular waveform	1	٨		
I _{FSM}		250	— A		
V _F	at 1 Apk, T _J = 125 °C	0.33	V		
TJ		- 55 to 150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	FCSP130LTR	UNITS		
Maximum DC reverse voltage	V _R	30	V		
Maximum working peak reverse voltage	V _{RWM}	30	v		



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_{PCB} = 120 °C, rectangular waveform		1.0	
Maximum peak one cycle non-repetitive surge current at 25 °C	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	220	А
		10 ms sine or 6 ms rect. pulse		21	
Non-repetitive avalanche energy	E _{AS}	$T_{J} = 25 \text{ °C}, I_{AS} = 2.0 \text{ A}, L = 5.0 \text{ mH}$		10	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2.0	А

ELECTRICAL CHARACTERISTICS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum forward voltage drop See fig. 1		at 1 A	T _J = 25 °C	0.41	0.45	- V
	V (1)	at 2 A		0.46	0.50	
	V _{FM} ⁽¹⁾	at 1 A	T _J = 125 °C	0.29	0.33	
		at 2 A		0.37	0.40	
Maximum reverse leakage current	ı (1)	T _J = 25 °C		30	100	μA
	T _J = 125 °C	V _R = Rated V _R	10	30	mA	
Maximum junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		-	210	pF
Maximum voltage rate of charge	dv/dt	Rated V _R		-	10 000	V/µs

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	T _J ⁽¹⁾		- 55 to 150	°C		
Maximum storage temperature range	T _{Stg}		- 55 10 150			
Typical thermal resistance, junction to PCB	R _{thJL} ⁽²⁾	DC operation	40	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}		62	0/₩		

Notes

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB





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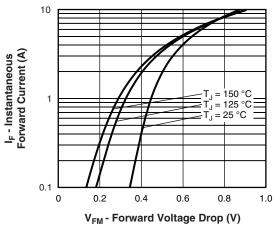
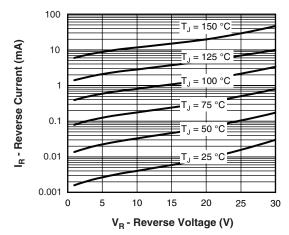
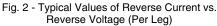
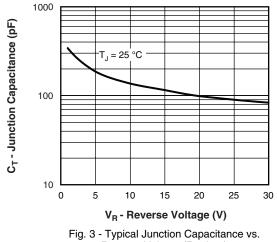


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)









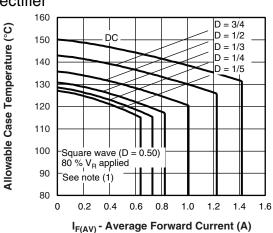


Fig. 4 - Maximum Allowable Case Temperature vs.



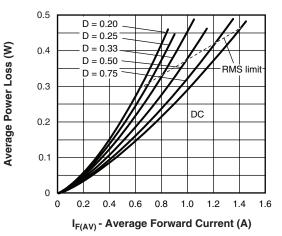
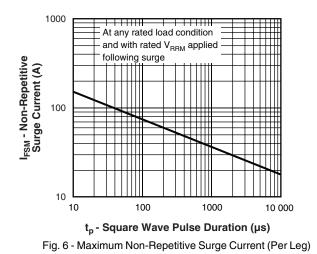


Fig. 5 - Forward Power Loss Characteristics (Per Leg)





⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at 80 % V_R applied



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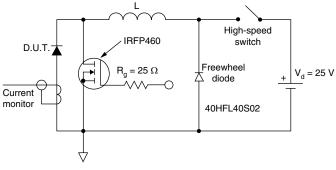
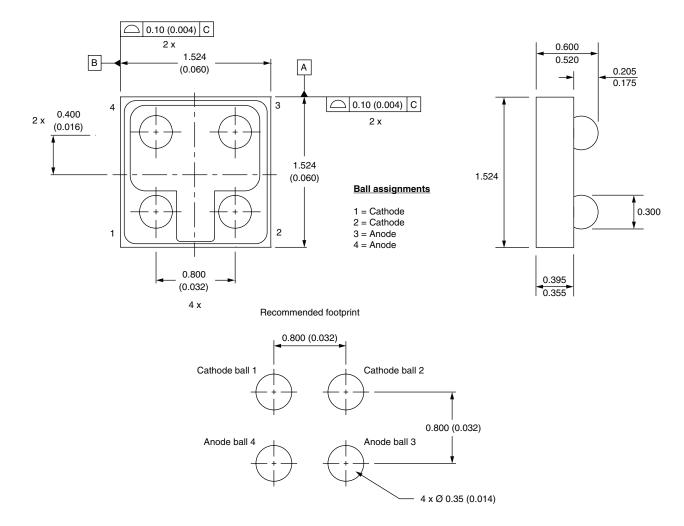


Fig. 7 - Unclamped Inductive Test Circuit

DIMENSIONS in millimeters (inches)



Notes

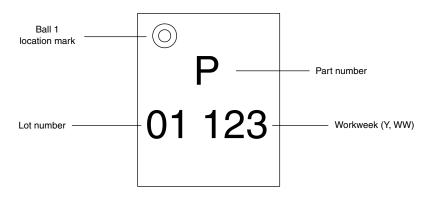
- Dimensioning and tolerancing per ASME Y14.5M-1994
- Controlling dimension: millimeter



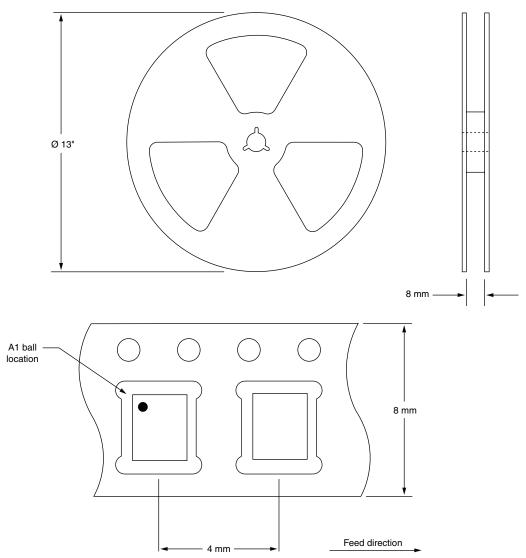
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PART MARKING INFORMATION



TAPE AND REEL INFORMATION



Conforms to EIA-481 and EIA-541



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